

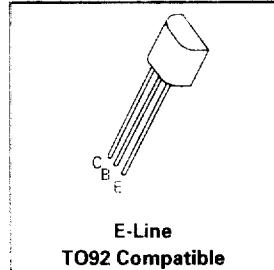
# NPN SILICON PLANAR MEDIUM POWER TRANSISTORS

ISSUE 2 – MARCH 1994

## FEATURES

- \* 140 Volt  $V_{CEO}$
- \* 1 Amp continuous current
- \*  $P_{tot} = 1$  Watt

**ZTX454**  
**ZTX455**



## ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	ZTX454	ZTX455	UNIT
Collector-Base Voltage	$V_{CBO}$	140	160	V
Collector-Emitter Voltage	$V_{CEO}$	120	140	V
Emitter-Base Voltage	$V_{EBO}$		5	V
Peak Pulse Current	$I_{CM}$		2	A
Continuous Collector Current	$I_C$		1	A
Power Dissipation at $T_{amb}=25^\circ\text{C}$	$P_{tot}$		1	W
Operating and Storage Temperature Range	$T_j, T_{stg}$		-55 to +200	°C

## ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ\text{C}$ ).

PARAMETER	SYMBOL	ZTX454		ZTX455		UNIT	CONDITIONS.
		MIN.	MAX.	MIN.	MAX.		
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	140		160		V	$I_C=100\mu\text{A}$
Collector-Emitter Sustaining Voltage	$V_{CEO(\text{sus})}$	120		140		V	$I_C=10\text{mA}^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5		5		V	$I_E=100\mu\text{A}$
Collector Cut-Off Current	$I_{CBO}$		0.1		0.1	$\mu\text{A}$	$V_{CB}=140\text{V}$ $V_{CB}=120\text{V}$
Emitter Cut-Off Current	$I_{EBO}$		0.1		0.1	$\mu\text{A}$	$V_{EB}=4\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$		0.7 1.0		0.7	V	$I_C=150\text{mA}, I_B=15\text{mA}$ $I_C=200\text{mA}, I_B=20\text{mA}$
Static Forward Current Transfer Ratio	$h_{FE}$	100 30 10†	300	100 10†	300		$I_C=150\text{mA}, V_{CE}=10\text{V}^*$ $I_C=200\text{mA}, V_{CE}=1\text{V}^*$ $I_C=1\text{A}, V_{CE}=10\text{V}^*$
Transition Frequency	$f_T$	100		100		MHz	$I_C=50\text{mA}, V_{CE}=10\text{V}$ $f=100\text{MHz}$
Output Capacitance	$C_{obo}$		15		15	pF	$V_{CB}=10\text{V}, f=1\text{MHz}$

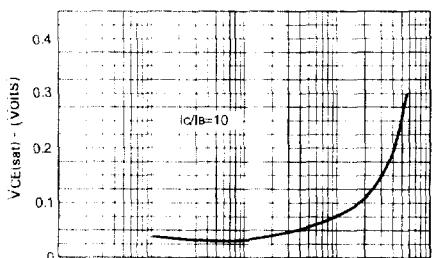
\* Measured under pulsed conditions. Pulse width=300μs. Duty cycle ≤ 2%

† Typical

# ZTX454

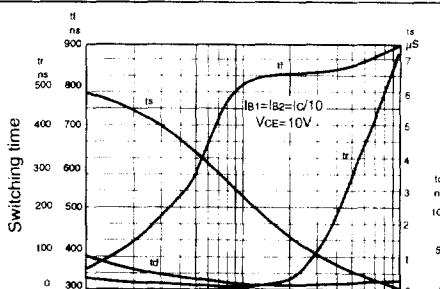
# ZTX455

## TYPICAL CHARACTERISTICS



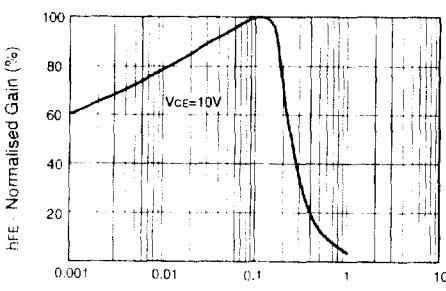
$I_C$  - Collector Current (Amps)

$V_{CE(sat)}$  v  $I_C$



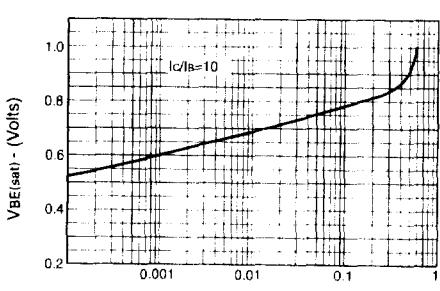
$I_C$  - Collector Current (Amps)

Typical Switching Speeds



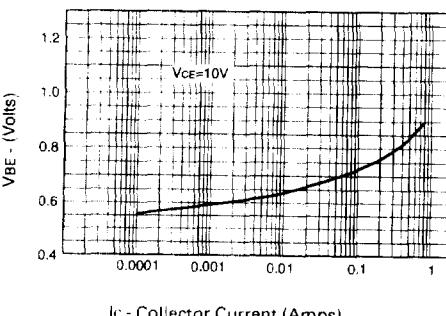
$I_C$  - Collector Current (Amps)

$hFE$  v  $I_C$



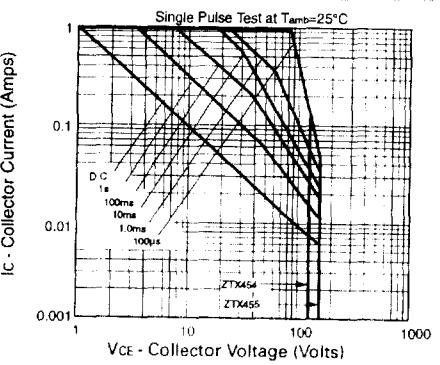
$I_C$  - Collector Current (Amps)

$V_{BE(sat)}$  v  $I_C$



$I_C$  - Collector Current (Amps)

$V_{BE(on)}$  v  $I_C$



Safe Operating Area